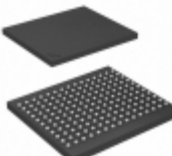


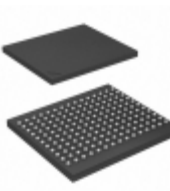
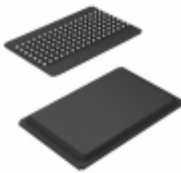
Spezifikationen	
Artikelnummer	71V65703S80BQ8
Hersteller	IDT (Integrated Device Technology)
Beschreibung	IC SRAM 9MBIT 8NS 165CABGA
Kategorie	Integrierte Schaltungen (ICs) > Erinnerung
Teilstatus	2626 pcs Stock
Spannungsversorgung	3.135 V ~ 3.465 V
Supplier Device-Gehäuse	165-CABGA (13x15)
Geschwindigkeit	8ns
Serie	-
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	165-TBGA
Betriebstemperatur	0°C ~ 70°C (TA)
Speichertyp	Volatile
Speichergröße	9Mb (256K x 36)
Speicherformat	SRAM
Schnittstelle	Parallel

sein:

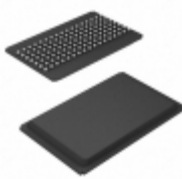
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Technology Inc
IC SRAM 9MBIT 8NS 165CABGA



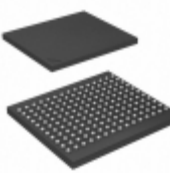
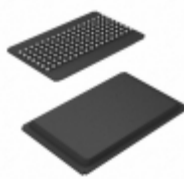
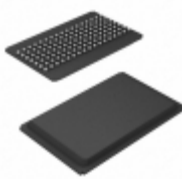
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 Technology Inc
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71V65703S80BGG8
 IDT, Integrated Device
 Technology Inc
 IC SRAM 9MBIT 8NS 119BGA



Mehr

Schlüsselwort (Integrated Device Technology)	71V65703S80BQ8 Datenblatt	71V65703S80BQ8-Datenblätter	71V65703S80BQ8 PDF	IDT (Integrated Device Technology)
				71V65703S80BQ8
71V65703S80BQ8 Electronic	71V65703S80BQ8-Komponenten	71V65703S80BQ8-Verteiler	71V65703S80BQ8-Bild	71V65703S80BQ8-Teil
71V65703S80BQ8 Preis	71V65703S80BQ8 Hersteller	71V65703S80BQ8 Bild	71V65703S80BQ8 Aktie	71V65703S80BQ8 Inventar
71V65703S80BQ8 Neu	71V65703S80BQ8 Original	71V65703S80BQ8 garantiert	71V65703S80BQ8 RFQ	71V65703S80BQ8 Online bestellen